

SK82C THRU SK810C

Reverse Voltage - 20 to 100 Volts Forward Current - 8.0 Ampere

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

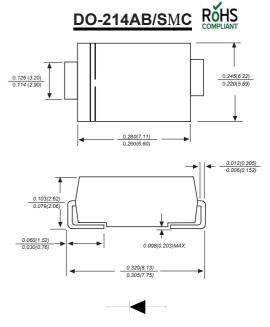
- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief,ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed:
 250 °C/10 seconds at terminals

Mechanical Data

Case: JEDEC DO-214AB/SMC molded plastic body Terminals: Solderable per MIL-STD-750,Method 2026 Polarity: Color band denotes cathode end Mounting

Position: Any

Weight: 0.0077 ounce, 0.22 grams



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	SYMBOLS	MDD SK82C	MDD	MDD	MDD	MDD	MDD	MDD	MDD	
Marking Code				i			SK86C	SK88C	SK810C	UNITS
Maximum repetitive peak reverse voltage	Vrrm	20	30	35	40	45	60	80	100	V
Maximum RMS voltage	VRMS	14	21	24.5	28	31.5	42	56	70	V
Maximum DC blocking voltage	VDC	20	30	35	40	45	60	80	100	V
Maximum average forward rectified current	aximum average forward rectified current I(AV) 8.0							А		
Peak forward surge current										
8.3ms single half sine-wave	IFSM	150						Α		
superimposed onrated load (JEDEC Method)										
Maximum instantaneous forward voltage at 8.0A	VF	0.45 0.55 0.70 0.85			85	V				
Maximum DC reverse current Ta=25℃		1.0							_	
at rated DCblocking voltage T _A =100°C	lR	50								mA
Typical junction capacitance (NOTE 1)	Сл	900 600					pF			
Typical thermal resistance (NOTE 2)	Reja	35						°C/W		
Operating junction temperature range	TJ	-55 to +150						°C		
Storage temperature range	Тѕтс	-55 to +150						℃		

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C. 2.P.C.B. mounted with 2.0"x2.0" (5.0x5.0cm) copper pad areas

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Typical Characterisitics

Fig.1 Forward Current Derating Curve

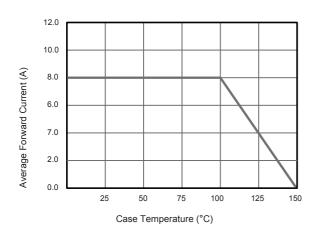


Fig.2 Typical Reverse Characteristics

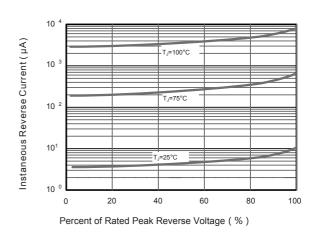


Fig.3 Typical Forward Characteristic

1000 500 T_{J=25°C} T_{J=25°}

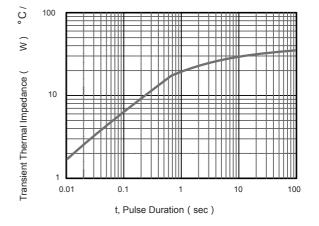
Fig.4 Typical Junction Capacitance

Forward Surage Current

200
175
150
125
100
75
50
8.3 ms Single Half Sine Wave (JEDEC Method)
1 10 100

Fig.5 Maximum Non-Repetitive Peak

Fig.6- Typical Transient Thermal Impedance



The curve above is for reference only.

Number of Cycles at 60Hz

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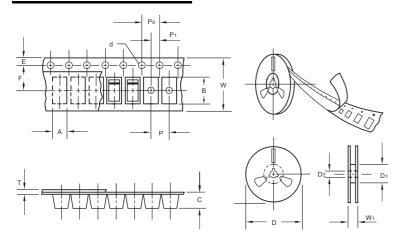


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Packing information

unit:mm



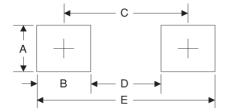
Item	Symbol	Tolerance	SMC		
Carrier width	Α	0.1	6.15		
Carrier length	В	0.1	8.41		
Carrier depth	С	0.1	2.42		
Sprocket hole	d	0.05	1.50		
13" Reel outside diameter	D	2.0	330.00		
13" Reel inner diameter	D1	min	50.00		
Feed hole diameter	D2	0.5	13.00		
Sprocket hole position	E	0.1	1.75		
Punch hole position	F	0.1	7.50		
Punch hole pitch	Р	0.1	8.00		
Sprocket hole pitch	P ₀	0.1	4.00		
Embossment center	P1	0.1	2.00		
Overall tape thickness	Т	0.1	0.25		
Tape width	W	0.3	16.00		
Reel width	W1	1.0	16.50		

Note: Devices are packed in accordance with EIA standar RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA, (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMC	13"	3,000	4.0	6000	190*190*41	330	365*365*340	42000	14.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
Α	4.3	0.170
В	4.1	0.160
С	7.9	0.311
D	3.8	0.150
Е	12	0.472

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